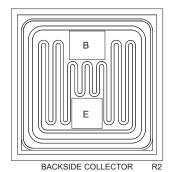


CP710V-MPSA92

PNP - High Voltage Transistor Die

The CP710V-MPSA92 is a silicon PNP transistor designed for high voltage applications.



MECHANICAL SPECIFICATIONS:

Die Size	26 x 26 MILS		
Die Thickness	7.1 MILS		
Base Bonding Pad Size	6.1 x 4.9 MILS		
Emitter Bonding Pad Size	5.2 x 5.2 MILS		
Top Side Metalization	AI – 30,000Å		
Back Side Metalization	Au – 9,000Å		
Scribe Alley Width	2.2 MILS		
Wafer Diameter	5 INCHES		
Gross Die Per Wafer	25,214		

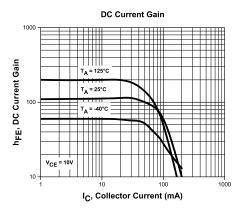
MAXIMUM F	RATINGS: (T _A =25°C)	SYMBOL		UNITS	
Collector-Ba	. / .	V_{CBO}	300	V	
Collector-Emitter Voltage		V_{CEO}	300	V	
Emitter-Base Voltage		V_{EBO}	5.0	V	
Continuous Collector Current		$I_{\mathbb{C}}$	500	mA	
Operating and Storage Junction Temperature		T _J , T _{stg}	-65 to +150	°C	
ELECTRICAL CHARACTERISTICS: (T _A =25°C)					
SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS	
ICBO	V _{CB} =200V		250	nA	
I _{EBO}	V _{EB} =3.0V		100	nA	
BV _{CBO}	I _C =100μA	300		V	
BV CEO	I _C =1.0mA	300		V	
BVEBO	I _E =100μA	5.0		V	
V _{CE(SAT)}	I _C =20mA, I _B =2.0mA		0.5	V	
V _{BE(SAT)}	I _C =20mA, I _B =2.0mA		0.9	V	
h _{FE}	V _{CE} =10V, I _C =1.0mA	25			
h _{FE}	V_{CE} =10V, I_{C} =10mA	40			
h_{FE}	V_{CE} =10V, I_{C} =30mA	25			
f _T	V_{CE} =20V, I_{C} =10mA, f=100MHz	50		MHz	
C_{ob}	V_{CB} =20V, I_E =0, f=1.0MHz		6.0	pF	

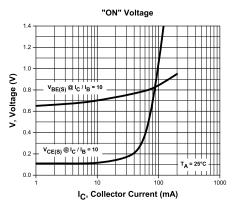
CP710V-MPSA92

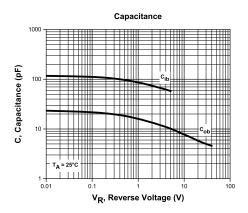
Typical Electrical Characteristics

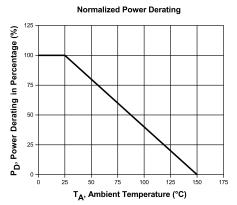


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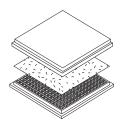






BARE DIE PACKING OPTIONS

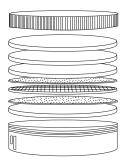




BARE DIE IN TRAY (WAFFLE) PACK

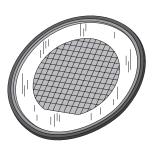
CT: Singulated die in tray (waffle) pack.
(example: CP211-PART NUMBER-CT)

CM: Singulated die in tray (waffle) pack 100% visually inspected as per MIL-STD-750, (method 2072 transistors, method 2073 diodes). (example: CP211-PART NUMBER-CM)



UNSAWN WAFER

WN: Full wafer, unsawn, 100% tested with reject die inked. (example: CP211-PART NUMBER-WN)



SAWN WAFER ON PLASTIC RING

WR: Full wafer, sawn and mounted on plastic ring, 100% tested with reject die inked.

(example: CP211-PART NUMBER-WR)

Please note: Sawn Wafer on Metal Frame (WS) is possible as a special order. Please contact your Central Sales Representative at 631-435-1110.



Visit the Central website for a complete listing of specifications: www.centralsemi.com/bdspecs

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

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